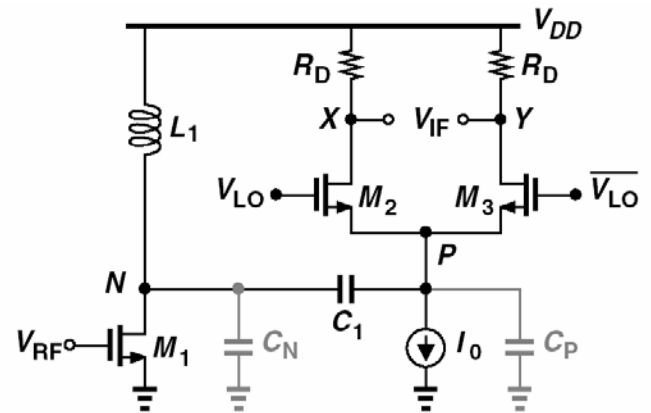
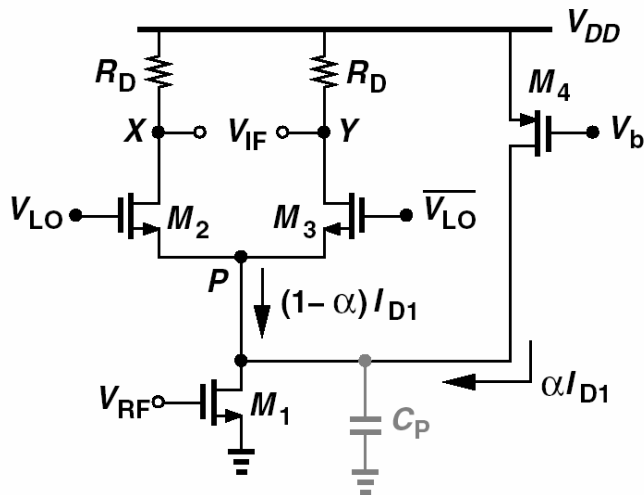


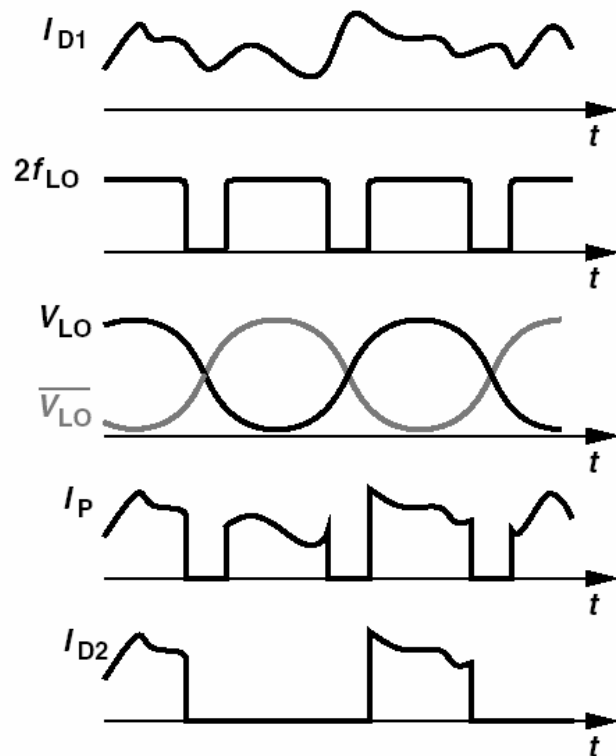
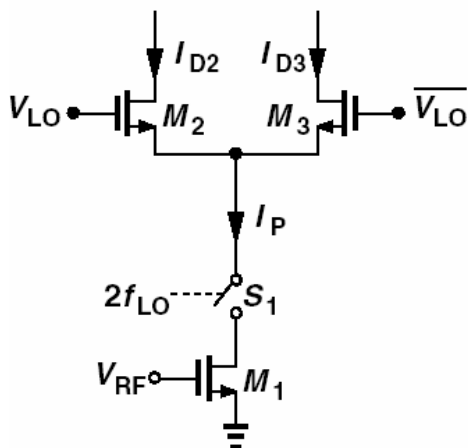
RF Mixers (III)

Methods of Reducing Flicker Noise in Active Mixers

Key observation: Reduce I_{SS} but without degrading gain, thermal NF, etc.



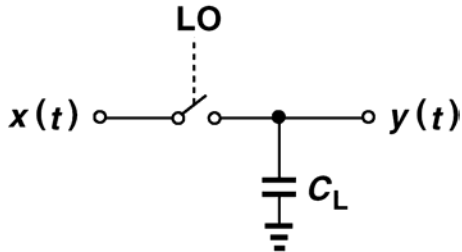
Or other clever schemes:



[Pullela, ISSCC06]

Nonlinearity in Mixers

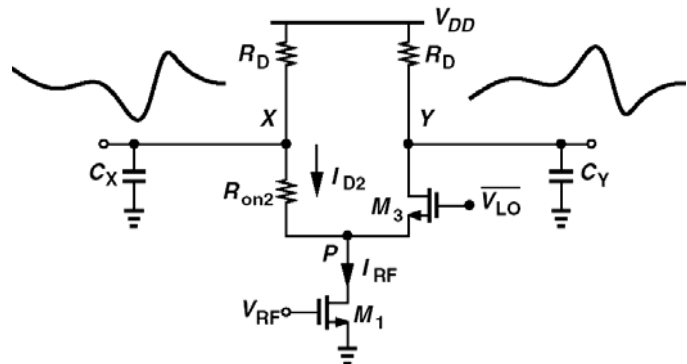
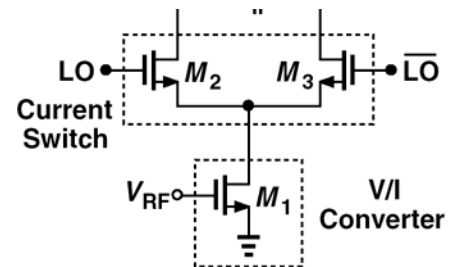
Voltage-driven passive mixers: The LO has a finite transition time, and the on-resistance varies during this time:



Active mixers:

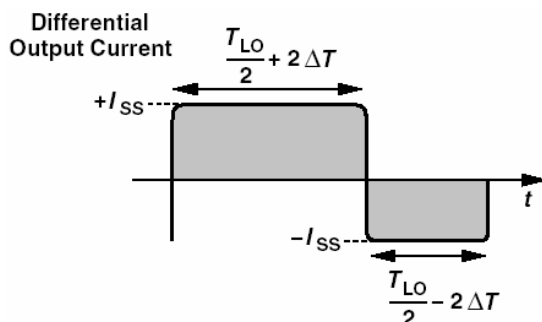
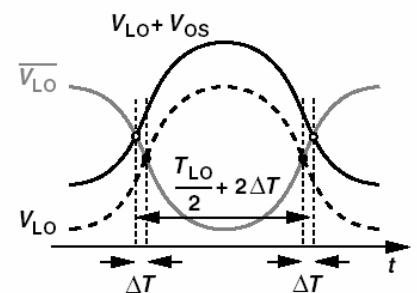
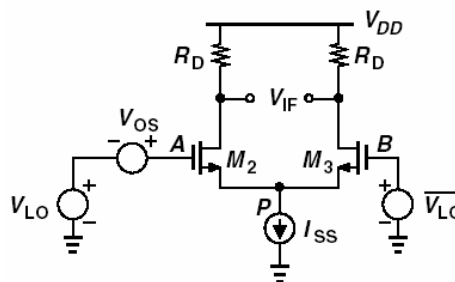
IP3:

- (1) V/I converter nonlinearity
- (2) When one diff pair device enters triode while the other is on:



IP2:

Asymmetries in the circuit, e.g., between diff pair devices:



Observations:

1. Should the effect of V_{OS} be similar to that of $1/f$ noise?

2. The differential output current contains a dc term equal to:

$$(4\Delta T/T_{LO})I_{SS} = V_{OS}I_{SS}/(\pi V_{p,LO})$$

3. If we replace I_{SS} with a V/I device and assume two tones, the input transistor generates a beat:

$$V_{RF} = V_m \cos \omega_1 t + V_m \cos \omega_2 t + V_{GS0}$$

$$I_{IM2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_m^2 \cos(\omega_1 - \omega_2)t$$

4. Need to equate the feedthrough amplitude to the fundamental amplitude:

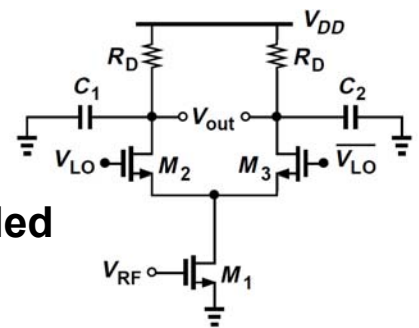
$$\frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{IIP2}^2 \frac{V_{OS} R_D}{\pi V_{p,LO}} = \frac{2}{\pi} g_{m1} R_D V_{IIP2}$$

The IIP2 is thus given by:

For example, if overdrive = 250 mV, LO peak swing = 300 mV, and $V_{OS} = 10$ mV, then IIP2 = 30 Vp (~ 40 dBm).

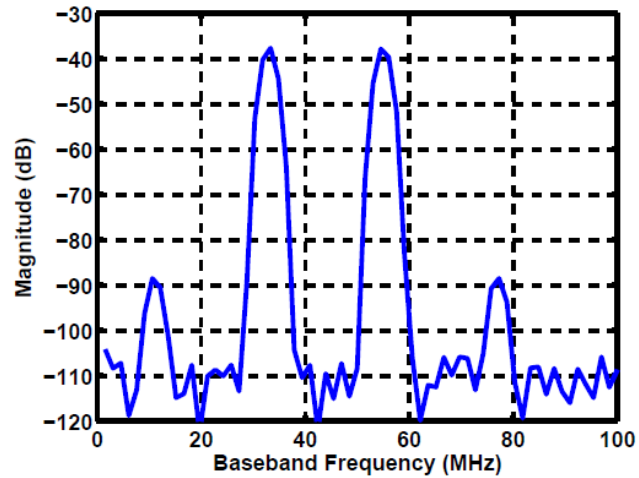
Active Mixer Design Example

- **Design Specs:**
 $V_{DD} = 1.2$ V, 65-nm CMOS, $I_{DD} = 2$ mA, single-ended
LO swing = 400 mV_p
- Design limited by voltage headroom; Assign:
 $V_{DS1} = 300$ mV $\rightarrow W_1 = 15$ μ m
 $g_{m1} = 12.75$ ms
 $V_{DS2,3,eq} = 150$ mV $\rightarrow W_{2,3} = 20$ μ m
 \rightarrow drop across $R_D = 600$ mV
 \rightarrow Choose $R_D = 500$ ohms
- Choose $C_1 = C_2 = 2$ pF to suppress LO feedthrough.

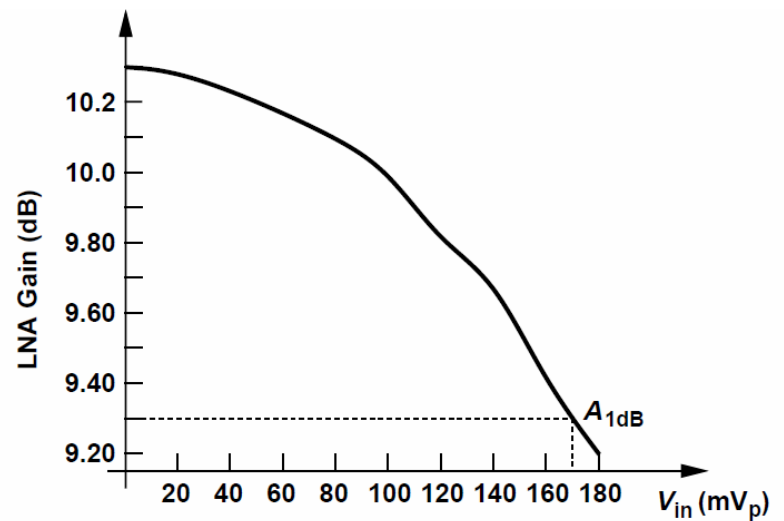


IIP3 Estimate:

Input peak amplitude: 40 mV



Compression Characteristic:



Quick Calculations:

- Voltage Conversion Gain:
- Noise Figure:

$$\begin{aligned}\overline{V_{n,in}^2} &= \pi^2 kT \left(\frac{\gamma}{g_{m1}} + \frac{2}{g_{m1}^2 R_D} \right) \\ &= 4.21 \times 10^{-18} \text{ V}^2/\text{Hz},\end{aligned}$$

$$\begin{aligned}\Rightarrow \text{NF}_{SSB} &= 1 + \frac{\overline{V_{n,in}^2}}{4kT R_S} \\ &= 6.1 (= 7.84 \text{ dB})\end{aligned}$$

$$A_v = \frac{2}{\pi} g_{m1} R_D$$

